

# PNP Epitaxial Silicon Transistor

## KSA928A

#### **Features**

- Audio Power Amplifier
- Complement to KSC2328A
- 3 W Output Application

## **ABSOLUTE MAXIMUM RATINGS**

(Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.) (Notes 1, 2)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-30	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-2	Α
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

## THERMAL CHARACTERISTICS

(Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.) (Note 3)

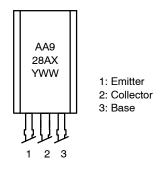
Symbol	Parameter	Value	Unit
P <sub>D</sub>	Power Dissipation	1000	mW
	Derate Above 25°C	8.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	125	°C/W

3. PCB size: FR-4, 76 mm  $\times$  114 mm  $\times$  1.57 mm (3.0 inch  $\times$  4.5 inch  $\times$  0.062 inch) with minimum land pattern size.



TO-92 3 LF CASE 135AM

#### MARKING DIAGRAM



A = Assembly Code A928A = Device Code X = O / Y YWW = Date Code

### **ORDERING INFORMATION**

Device	Package	Shipping
KSA928AOTA	TO-92 3 LF (Pb-Free)	2000 / Fan-Fold
KSA928AYTA	TO-92 3 LF (Pb-Free)	2000 / Fan–Fold

## KSA928A

## **ELECTRICAL CHARACTERISTICS**

(Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-30	-	-	V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{ mA}, I_B = 0$	-30	-	-	V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -1 \text{ mA}, I_C = 0$	-5	-	-	V
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = -30 \text{ V}, I_{E} = 0$	=	-	-100	nA
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = -5 \text{ V}, I_C = 0$	-	-	-100	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	100	-	320	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	-	-	-1.0	V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -1.5 \text{ A}, I_B = -30 \text{ mA}$	=	-	-2.0	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	=	120	-	MHz
C <sub>ob</sub>	Collector Output Capacitance	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	-	48	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **h**FE CLASSIFICATION

Classification	0	Υ	
h <sub>FE</sub>	100 ~ 200	160 ~ 320	

## KSA928A

## TYPICAL PERFORMANCE CHARACTERISTICS

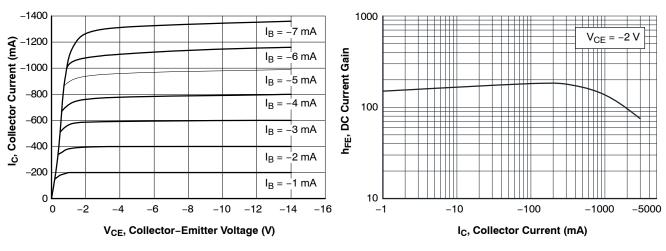
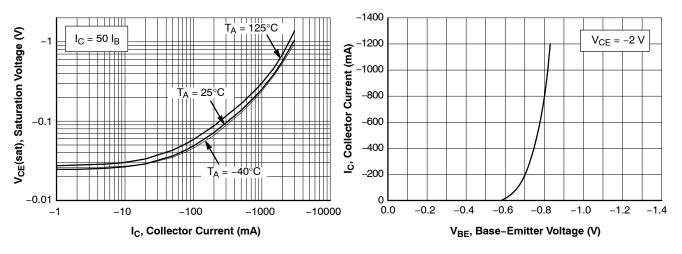


Figure 1. Static Characteristic

Figure 2. DC Current Gain



1 ms

Figure 3. Collector-Emitter Saturation Voltage

-10

-0.1

-0.01

-0.1

I<sub>C</sub>, Collector Current (A)

I<sub>C</sub> (Max) Pulse

I<sub>C</sub> (Max)

1.4 1.2 P<sub>C</sub>, Power Dissipation (W) 1.0 8.0 0.6 0.4 0.2 0.0 0 25 50 75 100 125 150 175

V<sub>CE</sub>, Collector-Emitter Voltage (V)

V<sub>CEO</sub> (Max)

-10

DC Operating

T<sub>C</sub> = 25°C

Figure 5. Safe Operating Area

Figure 4. Base-Emitter On Voltage

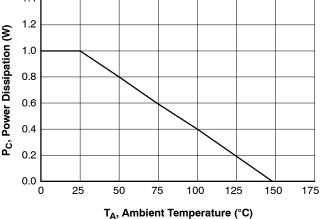
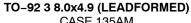


Figure 6. Power Derating

-100



CASE 135AM ISSUE B

**DATE 14 JAN 2021** 



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, GATE REMAINS AND TIE BAR PROTRUSIONS.
- 4. DIMENSION & AND &2 DOES NOT INCLUDE DAMBAR PROTRUSION.
  DIMENSION &2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	3.70	3.90	4.10	
A1	1.25	1.45	1.65	
b	0.35	0.50	0.60	
b2	0.62		0.78	
С	0.35	0.45	0.55	
D	7.80	8.00	8.20	
Ε	4.70	4.90	5.10	
E2	3.70	3.90	4.10	
е	1.27 BSC			
e2	2.50 BSC			
F	2.45 REF			
L	13.00 REF			
L2	1.50		1.90	
L3	2.60		3,40	
L4	10.40 REF			

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END VIEW

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